

## SANYO Semiconductors DATA SHEET

# LC87F2H08A CMOS IC 8K-byte FROM and 256-byte RAM integrated 8-bit 1-chip Microcontroller

### Overview

The SANYO LC87F2H08A is an 8-bit microcomputer that, centered around a CPU running at a minimum bus cycle time of 83.3ns, integrates on a single chip a number of hardware features such as 8K-byte flash ROM (On-board-programmable), 256-byte RAM, an On-chip-debugger, sophisticated 16-bit timers/counters (may be divided into 8-bit timers), a 16-bit timer/counter (may be divided into 8-bit timers/counters or 8-bit PWMs), two 8-bit timers with a prescaler, a base timer serving as a time-of-day clock, a high-speed clock counter, a synchronous SIO interface, an asynchronous/synchronous SIO interface, a UART interface (full duplex), two 12-bit PWM channels, a 12/8-bit 9-channel AD converter, a system clock frequency divider, an internal reset and a 20-source 10-vector interrupt feature.

#### **Features**

- ■Flash ROM
  - Capable of on-board programming with a wide range (2.2 to 5.5V) of voltage source.
  - Block-erasable in 128 byte units
  - Writable in 2-byte units
  - $8192 \times 8$  bits

### **■**RAM

- $256 \times 9$  bits
- ■Minimum Bus Cycle
  - 83.3ns (12MHz at V<sub>DD</sub>=2.7V to 5.5V)
  - 100ns (10MHz at V<sub>DD</sub>=2.2V to 5.5V)
  - 250ns (4MHz at V<sub>DD</sub>=1.8V to 5.5V)

Note: The bus cycle time here refers to the ROM read speed.

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### ■Minimum Instruction Cycle Time

- 250ns (12MHz at V<sub>DD</sub>=2.7V to 5.5V)
- 300ns (10MHz at V<sub>DD</sub>=2.2V to 5.5V)
- 750ns (4MHz at V<sub>DD</sub>=1.8V to 5.5V)

#### ■Ports

• Normal withstand voltage I/O ports

Ports whose I/O direction can be designated in 1-bit units 16 (Pin, P20, P21, P30, P31, P70 to P73)

Ports whose I/O direction can be designated in 4-bit units 8 (P0n)

• Dedicated oscillator ports/input ports 2 (CF1/XT1, CF2/XT2)

• Reset pin 1 (RES)

• Power pins 3 (VSS1, VSS2, VDD1)

#### **■**Timers

• Timer 0: 16-bit timer/counter with a capture register.

Mode 0: 8-bit timer with an 8-bit programmable prescaler (with an 8-bit capture register) × 2 channels

Mode 1: 8-bit timer with an 8-bit programmable prescaler (with an 8-bit capture register)

+ 8-bit counter (with an 8-bit capture register)

Mode 2: 16-bit timer with an 8-bit programmable prescaler (with a 16-bit capture register)

Mode 3: 16-bit counter (with a 16-bit capture register)

• Timer 1: 16-bit timer/counter that supports PWM/toggle outputs

Mode 0: 8-bit timer with an 8-bit prescaler (with toggle outputs) + 8-bit timer/

counter with an 8-bit prescaler (with toggle outputs)

Mode 1: 8-bit PWM with an 8-bit prescaler  $\times$  2 channels

Mode 2: 16-bit timer/counter with an 8-bit prescaler (with toggle outputs)

(toggle outputs also possible from the lower-order 8 bits)

Mode 3: 16-bit timer with an 8-bit prescaler (with toggle outputs)

(The lower-order 8 bits can be used as PWM)

- Timer 6: 8-bit timer with a 6-bit prescaler (with toggle outputs)
- Timer 7: 8-bit timer with a 6-bit prescaler (with toggle outputs)
- Base timer
  - 1) The clock is selectable from the subclock (32.768kHz crystal oscillation), system clock, and timer 0 prescaler output.
  - 2) Interrupts are programmable in 5 different time schemes

### ■High-Speed Clock Counter

- Can count clocks with a maximum clock rate of 20MHz (at a main clock of 10MHz).
- Can generate output real time.

#### **■**SIO

- SIO0: 8-bit Synchronous serial interface
  - 1) LSB first/MSB first mode selectable
  - 2) Built-in 8-bit baudrate generator (maximum transfer clock cycle=4/3tCYC)
- SIO1: 8-bit asynchronous/synchronous serial interface
  - Mode 0: Synchronous 8-bit serial I/O (2- or 3-wire configuration, 2 to 512 tCYC transfer clocks)
  - Mode 1: Asynchronous serial I/O (half-duplex, 8 data bits, 1 stop bit, 8 to 2048 tCYC baudrates)
  - Mode 2: Bus mode 1 (start bit, 8 data bits, 2 to 512 tCYC transfer clocks)
  - Mode 3: Bus mode 2 (start detect, 8 data bits, stop detect)

### **■**UART

- Full Duplex
- 7/8/9 bit data bits selectable
- 1 Stop bit (2 bits in continuous data transmission)
- Built-in baudrate generator
- ■AD Converter: 12 bits/8 bits × 9 channels
  - 12/8 bits AD converter resolution selectable

### ■PWM: Multifrequency 12-bit PWM × 2 channels

- ■Remote Control Receiver Circuit (sharing pins with P73, INT3, and T0IN)
  - Noise rejection function (noise filter time constant selectable from 1 tCYC/32 tCYC/128 tCYC)

### ■Clock Output Function

- Can generate clock outputs with a frequency of 1/1, 1/2, 1/4, 1/8, 1/16, 1/32, 1/64 of the source clock selected as the system clock.
- Can generate the source clock for the subclock

### ■Watchdog Timer

- External RC watchdog timer
- Interrupt and reset signals selectable

### **■**Interrupts

- 20 sources, 10 vector addresses
  - 1) Provides three levels (low (L), high (H), and highest (X)) of multiplex interrupt control. Any interrupt requests of the level equal to or lower than the current interrupt are not accepted.
  - 2) When interrupt requests to two or more vector addresses occur at the same time, the interrupt of the highest level takes precedence over the other interrupts. For interrupts of the same level, the interrupt into the smallest vector address takes precedence.

No.	Vector Address	Level	Interrupt Source
1	00003H	X or L	INT0
2	0000BH	X or L	INT1
3	00013H	H or L	INT2/T0L/INT4
4	0001BH	H or L	INT3/INT5/base timer
5	00023H	H or L	ТОН
6	0002BH	H or L	T1L/T1H
7	00033H	H or L	SIO0/UART1 receive
8	0003BH	H or L	SIO1/UART1 transmit
9	00043H	H or L	ADC/T6/T7/PWM4, PWM5
10	0004BH	H or L	Port 0

- Priority levels X > H > L
- Of interrupts of the same level, the one with the smallest vector address takes precedence.
- ■Subroutine Stack Levels: 128levels (The stack is allocated in RAM.)
- ■High-speed Multiplication/Division Instructions

16 bits × 8 bits
24 bits × 16 bits
16 bits ÷ 8 bits
24 bits ÷ 16 bits
16 bits ÷ 8 bits
16 bits ÷ 16 bits
17 tCYC execution time
18 tCYC execution time
19 tCYC execution time
10 tCYC execution time
10 tCYC execution time
11 tCYC execution time
12 tCYC execution time

### ■Oscillation Circuits

• Internal oscillation circuits

Low-speed RC oscillation circuit : For system clock (100kHz)
Medium-speed RC oscillation circuit : For system clock (1MHz)
Multifrequency RC oscillation circuit : For system clock (8MHz)

• External oscillation circuits

Hi-speed CF oscillation circuit: For system clock, with internal Rf

Low speed crystal oscillation circuit: For low-speed system clock, with internal Rf

- 1) The CF and crystal oscillation circuits share the same pins. The active circuit is selected under program control.
- 2) Both the CF and crystal oscillator circuits stop operation on a system reset. When the reset is released, only the CF oscillation circuit resumes operation.

### ■System Clock Divider Function

- Can run on low current.
- The minimum instruction cycle selectable from 300ns, 600ns, 1.2μs, 2.4μs, 4.8μs, 9.6μs, 19.2μs, 38.4μs, and 76.8μs (at a main clock rate of 10MHz).

### ■Internal reset function

- Power-on reset (POR) function
  - 1) POR reset is generated only at power-on time.
  - 2) The POR release level can be selected from 8 levels (1.67V, 1.97V, 2.07V, 2.37V, 2.57V, 2.87V, 3.86V, and 4.35V) through option configuration.
- Low-voltage detection reset (LVD) function
  - 1) LVD and POR functions are combined to generate resets when power is turned on and when power voltage falls below a certain level.
  - 2) The use/disuse of the LVD function and the low voltage threshold level (7 levels: 1.91V, 2.01V, 2.31V, 2.51V, 2.81V, 3.79V, 4.28V).

### ■Standby Function

- HALT mode: Halts instruction execution while allowing the peripheral circuits to continue operation.
  - 1) Oscillation is not halted automatically.
  - 2) There are three ways of resetting the HALT mode.
    - (1) Setting the reset pin to the low level
    - (2) System resetting by watchdog timer or low-voltage detection
    - (3) Occurrence of an interrupt
- HOLD mode: Suspends instruction execution and the operation of the peripheral circuits.
  - 1) The CF, RC and crystal oscillators automatically stop operation.
  - 2) There are four ways of resetting the HOLD mode.
    - (1) Setting the reset pin to the lower level.
    - (2) System resetting by watchdog timer or low-voltage detection
    - (3) Having an interrupt source established at either INT0, INT1, INT2, INT4 or INT5
    - \* INTO and INT1 HOLD mode reset is available only when level detection is set.
    - (4) Having an interrupt source established at port 0.
- X'tal HOLD mode: Suspends instruction execution and the operation of the peripheral circuits except the base timer.
  - 1) The CF and RC oscillator automatically stop operation.
  - 2) The state of crystal oscillation established when the X'tal HOLD mode is entered is retained.
  - 3) There are five ways of resetting the X'tal HOLD mode.
    - (1) Setting the reset pin to the low level.
    - (2) System resetting by watchdog timer or low-voltage detection.
    - (3) Having an interrupt source established at either INT0, INT1, INT2, INT4 or INT5
    - \* INTO and INT1 HOLD mode reset is available only when level detection is set.
    - (4) Having an interrupt source established at port 0.
    - (5) Having an interrupt source established in the base timer circuit.
    - Note: Available only when X'tal oscillation is selected.

### ■Onchip Debugger

- Supports software debugging with the IC mounted on the target board.
- Two channels of on-chip debugger pins are available to be compatible with small pin count devices. DBGP0 (P0), DBGP1 (P1)
- ■Data Security Function (flash versions only)
  - Protects the program data stored in flash memory from unauthorized read or copy.
    - Note: This data security function does not necessarily provide absolute data security.

### ■Package Form

• QFP36 (7×7): Lead-free type

### **■**Development Tools

• On-chip debugger: TCB87 type B + LC87F2H08A

**■**Programming Boards

Package	Programming boards			
QFP36(7×7)	W87F24Q			

■Flash ROM Programmer

Maker		Model	Supported version	Device	
	Single Programmer	AF9708 AF9709/AF9709B/AF9709C (Including Ando Electric Co., Ltd. models)	Rev 02.72 or later	LC87F2H08A	
Flash Support Group, Inc. (FSG)	Gang	AF9723/AF9723B(Main body) (Including Ando Electric Co., Ltd. models)	-	-	
	Programmer	AF9833(Unit) (Including Ando Electric Co., Ltd. models)	-	-	
Flash Support Group, Inc. (FSG)	In-circuit	AF9101/AF9103(Main body) (FSG models)			
+ SANYO (Note 1)	Programmer	SIB87(Inter Face Driver) (SANYO model)	(Note 2)	LC87F2H08A	
	Single/Gang Programmer	SKK/SKK Type B (SANYO FWS)	Application Version 1.04 or later	LC87F2H08A	
Sanyo	In-circuit/Gang Programmer	SKK-DBG Type B (SANYO FWS)	Chip Data Version 2.10 or later	LCO/F2HU6A	

For information about AF-Series:

Flash Support Group, Inc. TEL: +81-53-459-1050 E-mail: sales@j-fsg.co.jp

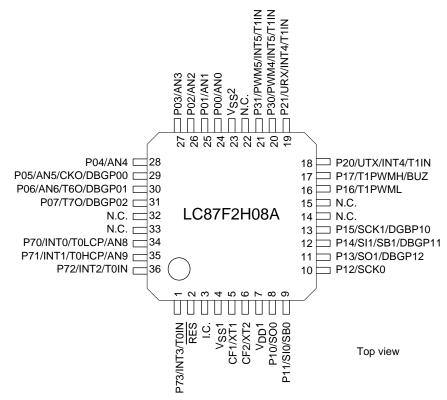
Note1: On-board-programmer from FSG (AF9101/AF9103) and serial interface driver from SANYO (SIB87) together can give a PC-less, standalone on-board-programming capabilities.

Note2: It needs a special programming devices and applications depending on the use of programming environment. Please ask FSG or SANYO for the information.

### **Package Dimensions**

unit : mm (typ) 3162C

### **Pin Assignment**



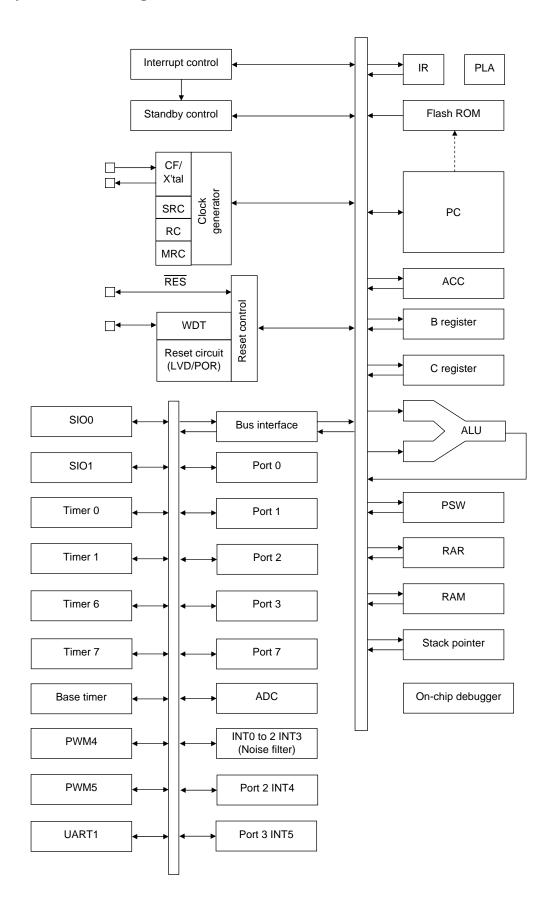
SANYO: QFP36 (7×7) "Lead-free Type"

QFP36	NAME
1	P73/INT3/T0IN
2	RES
3	I.C.
4	V <sub>SS</sub> 1
5	CF1/XT1
6	CF2/XT2
7	V <sub>DD</sub> 1
8	P10/SO0
9	P11/SI0/SB0
10	P12/SCK0
11	P13/SO1/DBGP12
12	P14/SI1/SB1/DBGP11
13	P15/SCK1/DBGP10
14	N.C.
15	N.C.
16	P16/T1PWML
17	P17/T1PWMH/BUZ
18	P20/UTX/INT4/T1IN

QFP36	NAME
19	P21/URX/INT4/T1IN
20	P30/PWM4/INT5/T1IN
21	P31/PWM5/INT5/T1IN
22	N.C.
23	V <sub>SS</sub> 2
24	P00/AN0
25	P01/AN1
26	P02/AN2
27	P03/AN3
28	P04/AN4
29	P05/AN5/CKO/DBGP00
30	P06/AN6/T6O/DBGP01
31	P07/T7O/DBGP02
32	N.C.
33	N.C.
34	P70/INT0/T0LCP/AN8
35	P71/INT1/T0HCP/AN9
36	P72/INT2/T0IN

Note I.C. and N.C. pins must be held open (disconnected).

### **System Block Diagram**



### **Pin Description**

Pin Name	I/O			De	scription			Option
V <sub>SS</sub> 1,V <sub>SS</sub> 2	-	- power supply	power supply pins					
V <sub>DD</sub> 1	-	+ power supply	+ power supply pin					
Port 0	I/O	• 8-bit I/O port						
P00 to P07		I/O specifiable	e in 4-bit units					
		Pull-up resiste	ors can be turned	on and off in 4	l-bit units.			
		HOLD reset in						
		Port 0 interrup	ot input					
		Pin functions						Yes
		P05: System						
		P06: Timer 6						
		P07: Timer 7	toggie output P06(AN6):AD cor	worter input				
			) to P07(DBGP0	=	igger () port			
Port 1	I/O	• 8-bit I/O port	) 10 1 07 (DBG1 02	2).On-onip debi	agger o port			
P10 to P17	- ""	I/O specifiable	e in 1-bit units					
FIOLOFIT		•	ors can be turned	on and off in 1	-bit units.			
		Pin functions						
		P10: SIO0 da	ta output	P1	4: SIO1 data inpu	it/bus I/O		Yes
		P11: SIO0 da	ta input/bus I/O	P1	5: SIO1 clock I/O			
		P12: SIO0 clo	ick I/O	P1	6: Timer 1 PWML	. output		
		P13: SIO1 da	ta output	P1	7: Timer 1 PWMF	l output/beeper	output	
		·	) to P13(DBGP12	2):On-chip deb	ugger 1 port			
Port 2	I/O	· ·						
P20 to P21		<ul><li>I/O specifiable in 1-bit units</li><li>Pull-up resistors can be turned on and off in 1-bit units.</li></ul>						
			ors can be turned	on and off in 1	-bit units.			
		<ul> <li>Pin functions</li> <li>P20: UART trans</li> </ul>	anemit					
		P21: UART re						
				reset input/time	er 1 event input/tir	mer 0L capture i	nput/	Yes
			mer 0H capture i					165
			owledge types	•				
			Dist	E I III	Rising &	111		
			Rising	Falling	Falling	H level	L level	
		INT4	enable	enable	enable	disable	disable	
Port 3	I/O	• 2-bit I/O port						
P30 to P31		I/O specifiable	e in 1-bit units					
		Pull-up resistor	ors can be turned	on and off in 1	-bit units.			
		Pin functions						
		P30: PWM4 o	•					
		P31: PWM5 o			4			
			M15 input/HOLD mer 0H capture i		er 1 event input/tir	ner or capture i	nput/	Yes
			mer un capture i owledge types	riput				
		interrupt ackn	owieuge types		Rising &			
			Rising	Falling	Falling	H level	L level	
		INT5	enable	enable	enable	disable	disable	
		1113	Cilable	GIADIC	Cilable	GIGADIE	GIGGDIE	

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Pin Name	I/O			Des	cription			Option		
Port 7	I/O	• 4-bit I/O port	•							
P70 to P73		I/O specifiable								
			Pull-up resistors can be turned on and off in 1-bit units.							
		Pin functions								
		P70: INT0 input	/HOLD reset in	put/timer 0L cap	ture input/watch	dog timer outpu	t			
		P71: INT1 input	/HOLD reset in	put/timer 0H cap	ture input					
		P72: INT2 input	/HOLD reset in	put/timer 0 even	t input/timer 0L o	capture input				
		P73: INT3 inpu	(input with nois	se filter)/timer 0	event input/time	OH capture inp	ut			
		P70(AN8),P71(	AN9) : AD conv	erter input				No		
		Interrupt acknow	wledge types				,			
			Rising	Falling	Rising & Falling	H level	L level			
		INT0	enable	enable	disable	enable	enable			
		INT1	enable	enable	disable	enable	enable			
		INT2	enable	enable	enable	disable	disable			
		INT3	enable	enable	enable	disable	disable			
RES	I/O	External reset In	out/internal rese	et output				No		
CF1/XT1		Ceramic resona	ator or 32.768kH	Iz crystal oscilla	tor input pin					
	'	Pin function		•				No		
		General-purpose	input port							
CF2/XT2	I/O	Ceramic resona	ator or 32.768kH	Iz crystal oscilla	tor output pin					
		Pin function						No		
		General-purpose	input port							

### **Port Output Types**

The table below lists the types of port outputs and the presence/absence of a pull-up resistor.

Data can be read into any input port even if it is in the output mode.

Port Name	Option selected in units of	Option type	Output type	Pull-up resistor
P00 to P07	1 bit	1	CMOS	Programmable (Note 1)
		2	Nch-open drain	No
P10 to P17	1 bit	1	CMOS	Programmable
		2	Nch-open drain	Programmable
P20 to P21	1 bit	1	CMOS	Programmable
		2	Nch-open drain	Programmable
P30 to P31	1 bit	1	CMOS	Programmable
		2	Nch-open drain	Programmable
P70	-	No	Nch-open drain	Programmable
P71 to P73	-	No	CMOS	Programmable

Note 1: The control of the presence or absence of the programmable pull-up resistors for port 0 and the switching between low-and high-impedance pull-up connection is exercised in nibble (4-bit) units (P00 to 03 or P04 to 07).

Note: Be sure to electrically short-circuit between the VSS1 and VSS2 pins.

### **User Option Table**

Option Name	Option to be Applied on	Flash-ROM Version	Option Selected in Units of	Option Selection
Port output type	P00 to P07	0	1 bit	CMOS
				Nch-open drain
	P10 to P17	0	1 bit	CMOS
				Nch-open drain
	P20 to P21	0	1 bit	CMOS
				Nch-open drain
	P30 to P31	0	1 bit	CMOS
				Nch-open drain
Program start	-	0	-	00000h
address				01E00h
Low-voltage	Detect function	0	-	Enable:Use
detection reset				Disable:Not Used
function	Detect level	0	-	7-level
Power-on reset function	Power-On reset level	0	-	8-level

### **Recommended Unused Pin Connections**

Dest News	Recommended Unused Pin Connections					
Port Name	Board	Software				
P00 to P07	Open	Output low				
P10 to P17	Open	Output low				
P20 to P21	Open	Output low				
P30 to P31	Open	Output low				
P70 to P73	Open	Output low				
CF1/XT1	Pulled low with a 100kΩ resistor or less	General-purpose input port				
CF2/XT2	Pulled low with a $100k\Omega$ resistor or less	General-purpose input port				

### On-chip Debugger pin connection requirements

For the treatment of the on-chip debugger pins, refer to the separately available documents entitled "RD87 on-chip debugger installation manual" and "LC872000 series on-chip debugger pin connection requirements"

Note: Be sure to electrically short-circuit between the  $V_{\mbox{\footnotesize{SS}}}1$  and  $V_{\mbox{\footnotesize{SS}}}2$  pins.

### Absolute Maximum Ratings at Ta = 25°C, $V_{SS}1 = V_{SS}2 = 0V$

	Parameter	Cumbal	Pin/Remarks	Conditions		Specification		ication	
	Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
Maximum supply voltage		V <sub>DD</sub> max	V <sub>DD</sub> 1			-0.3		+6.5	
Input voltage Input/output voltage		VI	CF1, CF2			-0.3		V <sub>DD</sub> +0.3	V
		V <sub>IO</sub>	Ports 0, 1, 2, 3 Port 7			-0.3		V <sub>DD</sub> +0.3	
	Peak output current	IOPH(1)	Ports 0, 1, 2, 3	CMOS output select Per 1 applicable pin		-10			
Ħ		IOPH(2)	P71 to P73	Per 1 applicable pin		-5			
High level output current	Mean output current	IOMH(1)	Ports 0, 1, 2, 3	CMOS output select Per 1 applicable pin		-7.5			
outpu	(Note 1-1)	IOMH(2)	P71 to P73	Per 1 applicable pin		-3			
vel c	Total output	ΣΙΟΑΗ(1)	P71 to P73	Total of all applicable pins		-10			
Jh le	current	ΣΙΟΑΗ(2)	P10 to P14	Total of all applicable pins		-20			
Hi		ΣΙΟΑΗ(3)	P15 to P17 Ports 0, 2, 3	Total of all applicable pins		-20			
		ΣΙΟΑΗ(4)	Ports 0, 1, 2, 3	Total of all applicable pins		-25			
	Peak output current	IOPL(1)	P02 to P07 Ports 1, 2, 3	Per 1 applicable pin				20	mA
		IOPL(2)	P00, P01	Per 1 applicable pin				30	
		IOPL(3)	Port 7	Per 1 applicable pin				10	
Low level output current	Mean output	IOML(1)	P02 to P07 Ports 1, 2, 3	Per 1 applicable pin				15	
ıtput	(Note 1-1)	IOML(2)	P00, P01	Per 1 applicable pin				20	
el or		IOML(3)	Port 7	Per 1 applicable pin				7.5	
v lev	Total output	ΣIOAL(1)	Port 7	Total of all applicable pins				15	
Lov	current	ΣIOAL(2)	Port 0	Total of all applicable pins				40	
		ΣIOAL(3)	P10 to P14	Total of all applicable pins				35	
		ΣIOAL(4)	Ports 1, 2, 3	Total of all applicable pins				40	
		ΣIOAL(5)	Ports 0, 1, 2, 3	Total of all applicable pins				70	
	wer ssipation	Pd max(1)	QFP36(7×7)	Ta=-40 to +85°C Package only				120	
		Pd max(2)		Ta=-40 to +85°C Package with thermal resistance board (Note 1-2)				275	mW
	erating ambient mperature	Topr				-40		+85	
	orage ambient	Tstg				-55		+125	°C

Note 1-1: The mean output current is a mean value measured over 100ms.

Note 1-2: SEMI standards thermal resistance board (size: 76.1×114.3×1.6tmm, glass epoxy) is used.

### Allowable Operating Conditions at Ta = -40 °C to +85 °C, $V_SS1 = V_SS2 = 0V$

				55	- 55			
Parameter	Symbol	Pin/Remarks	Conditions			Specif	ication	ı
				V <sub>DD</sub> [V]	min	typ	max	unit
Operating	V <sub>DD</sub> (1)	V <sub>DD</sub> 1	0.245μs ≤ tCYC ≤ 200μs		2.7		5.5	
supply voltage	V <sub>DD</sub> (2)		0.294μs ≤ tCYC ≤ 200μs		2.2		5.5	
(Note 2-1)	V <sub>DD</sub> (3)		0.735μs ≤ tCYC ≤ 200μs		1.8		5.5	
Memory sustaining supply voltage	VHD	V <sub>DD</sub> 1	RAM and register contents sustained in HOLD mode.		1.6			
High level input voltage	V <sub>IH</sub> (1)	Ports 1, 2, 3, P71 to P73 P70 port input/ interrupt side		1.8 to 5.5	0.3V <sub>DD</sub> +0.7		V <sub>DD</sub>	
	V <sub>IH</sub> (2)	Ports 0		1.8 to 5.5	0.3V <sub>DD</sub> +0.7		VDD	
	V <sub>IH</sub> (3)	Port 70 watchdog timer side		1.8 to 5.5	0.9V <sub>DD</sub>		V <sub>DD</sub>	٧
	V <sub>IH</sub> (4)	CF1, RES		1.8 to 5.5	0.75V <sub>DD</sub>		VDD	
Low level	V <sub>IL</sub> (1)	Ports 1, 2, 3,		4.0 to 5.5				
input voltage	· IL(·/	P71 to P73 P70 port input/ interrupt side		1.8 to 4.0	V <sub>SS</sub>		0.2V <sub>DD</sub>	
	V <sub>IL</sub> (2)	Ports 0		4.0 to 5.5	Vac		0.15\/55±0.4	
	V (L(2)	1 013 0			V <sub>SS</sub>			
	V <sub>IL</sub> (3)	Port 70 watchdog		1.8 to 4.0	V <sub>SS</sub>			
		timer side						
	V <sub>IL</sub> (4)	CF1, RES		1.8 to 5.5	V <sub>SS</sub>		0.25V <sub>DD</sub>	
Instruction	tCYC			2.7 to 5.5	0.245		200	
cycle time	(Note 2-2)			2.2 to 5.5	0.294		200	μs
(Note 2-1)				1.8 to 5.5	0.735		200	
External	FEXCF	CF1	CF2 pin open	2.7 to 5.5	0.1		12	
system clock frequency			System clock frequency division ratio=1/1     External system clock duty=50±5%	1.8 to 5.5	0.1		4	
			CF2 pin open	3.0 to 5.5	0.2		24.4	MHz
			System clock frequency division ratio=1/2      The system clock frequency division     The system clock frequency division division     The system clock frequency division d	2.0 to 5.5	0.2		VDD VDD VDD 0.1VDD+0.4 0.2VDD 0.15VDD+0.4 0.2VDD 0.8VDD-1.0 0.25VDD 200 200 200 200 212 4 24.4 8 8 12 10 4 4 0.8856 0.856	
Oscillation frequency	FmCF(1)	CF1, CF2	External system clock duty=50±5%     12MHz ceramic oscillation     See Fig. 1.	2.7 to 5.5		12		
range (Note 2-3)	FmCF(2)	CF1, CF2	10MHz ceramic oscillation See Fig. 1.	2.2 to 5.5		10		
	FmCF(3)	CF1, CF2	4MHz ceramic oscillation. CF oscillation normal amplifier size selected. See Fig. 1. (CFLAMP=0)	1.8 to 5.5		4		
			4MHz ceramic oscillation. CF oscillation low amplifier size selected. (CFLAMP=1) See Fig. 1.	2.2 to 5.5		4		MHz
	FmMRC		Frequency variable RC oscillation. 1/2 frequency division ration. (RCCTD=0) (Note 2-4)	2.7 to 5.5	7.44	8.0	8.56	
	FmRC		Internal medium-speed RC oscillation	1.8 to 5.5	0.5	1.0	2.0	
	FmSRC		Internal low-speed RC oscillation	1.8 to 5.5	50	100	200	
	FsX'tal	XT1, XT2	32.768kHz crystal oscillation See Fig. 2.	1.8 to 5.5		32.768		kHz
	•	•	•	•	•	•	•	

- Note 2-1: V<sub>DD</sub> must be held greater than or equal to 2.2V in the flash ROM onboard programming mode.
- Note 2-2: Relationship between tCYC and oscillation frequency is 3/FmCF at a division ratio of 1/1 and 6/FmCF at a division ratio of 1/2.
- Note 2-3: See Tables 1 and 2 for the oscillation constants.
- Note 2-4: When switching the system clock, allow an oscillation stabilization time of  $100\mu s$  or longer after the multifrequency RC oscillator circuit transmits from the "oscillation stopped" to "oscillation enabled" state.

### **Electrical Characteristics** at $Ta = -40^{\circ}C$ to $+85^{\circ}C$ , $V_{SS}1 = V_{SS}2 = 0V$

			7 55	טט					
Parameter	Symbol	Pin/Remarks	Conditions		Specification				
Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit	
High level input current	I <sub>IH</sub> (1)	Ports 0, 1, 2, 3 Port 7 RES	Output disabled Pull-up resistor off VIN=VDD (Including output Tr's off leakage current)	1.8 to 5.5			1		
	I <sub>IH</sub> (2)	CF1	V <sub>IN</sub> =V <sub>DD</sub>	1.8 to 5.5			15		
Low level input current	I <sub>IL</sub> (1)	Ports 0, 1, 2, 3 Port 7 RES	Output disabled Pull-up resistor off VIN=VSS (Including output Tr's off leakage current)	1.8 to 5.5	-1			• µА	
	I <sub>IL</sub> (2)	CF1	V <sub>IN</sub> =V <sub>SS</sub>	1.8 to 5.5	-15				
High level output	V <sub>OH</sub> (1)	Ports 0, 1, 2	I <sub>OH</sub> =-1mA	4.5 to 5.5	V <sub>DD</sub> -1				
voltage	V <sub>OH</sub> (2)	P71 to P73	I <sub>OH</sub> =-0.35mA	2.7 to 5.5	V <sub>DD</sub> -0.4				
	V <sub>OH</sub> (3)		I <sub>OH</sub> =-0.15mA	1.8 to 5.5	V <sub>DD</sub> -0.4				
	V <sub>OH</sub> (4)	Port 3	I <sub>OH</sub> =-6mA	4.5 to 5.5	V <sub>DD</sub> -1				
	V <sub>OH</sub> (5)		I <sub>OH</sub> =-1.4mA	2.7 to 5.5	V <sub>DD</sub> -0.4				
	V <sub>OH</sub> (6)		I <sub>OH</sub> =-0.8mA	1.8 to 5.5	V <sub>DD</sub> -0.4				
Low level output	V <sub>OL</sub> (1)	Ports 0, 1, 2, 3	I <sub>OL</sub> =10mA	4.5 to 5.5			1.5	١,,	
voltage	V <sub>OL</sub> (2)		I <sub>OL</sub> =1.4mA	2.7 to 5.5			0.4	V	
	V <sub>OL</sub> (3)		I <sub>OL</sub> =0.8mA	1.8 to 5.5			0.4		
	V <sub>OL</sub> (4)	Port 7	I <sub>OL</sub> =1.4mA	2.7 to 5.5			0.4		
	V <sub>OL</sub> (5)		I <sub>OL</sub> =0.8mA	1.8 to 5.5			0.4		
	V <sub>OL</sub> (6)	P00, P01	I <sub>OL</sub> =25mA	4.5 to 5.5			1.5		
	V <sub>OL</sub> (7)		I <sub>OL</sub> =4mA	2.7 to 5.5			0.4		
	V <sub>OL</sub> (8)		I <sub>OL</sub> =2mA	1.8 to 5.5			0.4		
Pull-up resistance	Rpu(1)	Ports 0, 1, 2, 3	V <sub>OH</sub> =0.9V <sub>DD</sub>	4.5 to 5.5	15	35	80		
	Rpu(2)	Port 7	When Port 0 selected low-impedance pull-up.	1.8 to 4.5	18	50	230	1.0	
	Rpu(3)	Port 0	V <sub>OH</sub> =0.9V <sub>DD</sub> When Port 0 selected high-impedance pull-up.	1.8 to 5.5	100	210	400	kΩ	
Hysteresis voltage	VHYS(1)	Ports 1, 2, 3, 7		2.7 to 5.5		0.1V <sub>DD</sub>			
	VHYS(2)	RES		1.8 to 2.7		0.07V <sub>DD</sub>		V	
Pin capacitance	СР	All pins	For pins other than that under test:  VIN=VSS f=1MHz Ta=25°C	1.8 to 5.5		10		pF	

### Serial I/O Characteristics at $Ta = -40^{\circ}C$ to $+85^{\circ}C$ , $V_{SS}1 = V_{SS}2 = 0V$

### 1. SIO0 Serial I/O Characteristics (Note 4-1-1)

	-	Parameter	Cymbol	Pin/	Conditions			Speci	fication	
	Г	Parameter	Symbol	Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
	ا ا	Frequency	tSCK(1)	SCK0(P12)	• See Fig. 5.		2			
	Input clock	Low level	tSCKL(1)				1			
	put (	pulse width				1.8 to 5.5	•			tCYC
Sock	<u> </u>	High level pulse width	tSCKH(1)				1			
Serial clock		Frequency	tSCK(2)	SCK0(P12)	CMOS output selected		4/3			
Se	ock	Low level	tSCKL(2)		• See Fig. 5.		1,0			
	Output clock	pulse width	ISONE(2)		<b>3</b> .	1.8 to 5.5		1/2		+0.014
	Outp	High level	tSCKH(2)					1/2		tSCK
		pulse width						1/2		
Ħ	Da	ta setup time	tsDI(1)	SB0(P11),	Must be specified with					
Serial input				SI0(P11)	respect to rising edge of SIOCLK.	1.8 to 5.5	0.05			
Seria	Da	ta hold time	thDI(1)		• See Fig. 5.	1.0 10 0.0				
U)			, ,		· ·		0.05			
		Output delay	tdD0(1)	SO0(P10),	Continuous data				(1/3)tCYC	
	Input clock	time		SB0(P11)	transmission/reception mode				+0.08	
1	but (				(Note 4-1-2)					μs
Serial output	ī		tdD0(2)		Synchronous 8-bit mode     (Note 4-1-2)				1tCYC +0.08	
<u>a</u>			tdD0(3)	1	(Note 4-1-2)	1.8 to 5.5			+0.00	
Seri	ock		(dD0(3)		(Note 4-1-2)					
	ut cl								(1/3)tCYC	
	Output clock								+0.08	

Note 4-1-1: These specifications are theoretical values. Add margin depending on its use.

Note 4-1-2: Must be specified with respect to falling edge of SIOCLK. Must be specified as the time to the beginning of output state change in open drain output mode. See Fig. 5.

### 2. SIO1 Serial I/O Characteristics (Note 4-2-1)

		Parameter	Symbol	Pin/	Conditions			Spec	ification	
		Parameter	Symbol	Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
	ĸ	Frequency	tSCK(3)	SCK1(P15)	See Fig. 5.		2			
	Input clock	Low level pulse width	tSCKL(3)			1.8 to 5.5	1			10)(0
Serial clock	lu	High level pulse width	tSCKH(3)				1			tCYC
Serial	ock	Frequency	tSCK(4)	SCK1(P15)	CMOS output selected     See Fig. 5.		2			
	Output clock	Low level pulse width	tSCKL(4)			1.8 to 5.5		1/2		tSCK
	Õ	High level pulse width	tSCKH(4)					1/2		ISCK
Serial input	Da	ata setup time	tsDI(2)	SB1(P14), SI1(P14)	Must be specified with respect to rising edge of SIOCLK.     See Fig. 5.	404.55	0.05			
Serial	Da	ata hold time	thDI(2)			1.8 to 5.5	0.05			
Serial output	Ou	tput delay time	tdD0(4)	SO1(P13), SB1(P14)	Must be specified with respect to falling edge of SIOCLK.     Must be specified as the time to the beginning of output state change in open drain output mode.     See Fig. 5.	1.8 to 5.5			(1/3)tCYC +0.08	μѕ

Note 4-2-1: These specifications are theoretical values. Add margin depending on its use.

### Pulse Input Conditions at Ta = -40°C to +85°C, $V_{SS}1 = V_{SS}2 = 0V$

Parameter	Symbol	Pin/Remarks	Conditions			Speci	fication	
Farameter	Symbol	Fill/Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
High/low level	tPIH(1)	INT0(P70),	Interrupt source flag can be set.					
pulse width	tPIL(1)	INT1(P71),	Event inputs for timer 0 or 1 are					
		INT2(P72),	enabled.	1.8 to 5.5	1			
		INT4(P20 to P21),						
		INT5(P30 to P31)						
	tPIH(2)	INT3(P73) when noise	Interrupt source flag can be set.					
	tPIL(2)	filter time constant is	Event inputs for timer 0 are	1.8 to 5.5	2			tCYC
		1/1	enabled.					icic
	tPIH(3)	INT3(P73) when noise	Interrupt source flag can be set.					
	tPIL(3)	filter time constant is	Event inputs for timer 0 are	1.8 to 5.5	64			
		1/32	nabled.					
	tPIH(4)	INT3(P73) when noise	Interrupt source flag can be set.					
	tPIL(4)	filter time constant is	Event inputs for timer 0 are	1.8 to 5.5	256			
		1/128	enabled.					
	tPIL(5)	RES	Resetting is enabled.	1.8 to 5.5	200			μs

### AD Converter Characteristics at $V_{SS}1 = V_{SS}2 = 0V$

### <12bits AD Converter Mode/Ta = -40°C to +85°C >

Parameter	Cumbal	Pin/Remarks	Conditions			Specific	cation	
Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
Resolution	N	AN0(P00) to		2.4 to 5.5		12		bit
Absolute	ET	AN6(P06),	(Note 6-1)	3.0 to 5.5			±16	
accuracy		AN8(P70), AN9(P71)	(Note 6-1) • Ta=-10 to +50°C	2.4 to 3.6			±20	LSB
Conversion time	TCAD		See Conversion time calculation	4.0 to 5.5	32		115	
			formulas. (Note 6-2)	3.0 to 5.5	64		115	
			See Conversion time calculation formulas. (Note 6-2)     Ta=-10 to +50°C	2.4 to 3.6	410		425	μs
Analog input voltage range	VAIN			2.4 to 5.5	V <sub>SS</sub>		V <sub>DD</sub>	٧
Analog port	IAINH		VAIN=V <sub>DD</sub>	2.4 to 5.5			1	
input current	IAINL	]	VAIN=V <sub>SS</sub>	2.4 to 5.5	-1			μΑ

### <8bits AD Converter Mode/Ta = -40°C to +85°C >

Danamatan	O was boat	Pin/Remarks	Conditions			Specifi	cation	
Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
Resolution	N	AN0(P00) to		2.4 to 5.5		8		bit
Absolute accuracy	ET	AN6(P06) AN8(P70)	(Note 6-1)	2.4 to 5.5			±1.5	LSB
Conversion time	TCAD	AN9(P71)	See Conversion time calculation	4.0 to 5.5	20		90	
			formulas. (Note 6-2)	3.0 to 5.5	40		90	
			See Conversion time calculation formulas. (Note 6-2)     Ta=-10 to +50°C	2.4 to 3.6	250		265	μѕ
Analog input voltage range	VAIN			2.4 to 5.5	V <sub>SS</sub>		V <sub>DD</sub>	V
Analog port	IAINH		VAIN=V <sub>DD</sub>	2.4 to 5.5			1	4
input current	IAINL		VAIN=VSS	2.4 to 5.5	-1			μΑ

Conversion time calculation formulas:

12bits AD Converter Mode: TCAD(Conversion time) =  $((52/(AD \text{ division ratio}))+2)\times(1/3)\times tCYC$ 8bits AD Converter Mode: TCAD(Conversion time) =  $((32/(AD \text{ division ratio}))+2)\times(1/3)\times tCYC$ 

External oscillation	Operating supply voltage range	System division ratio	Cycle time	AD division ratio	AD conversion time (TCAD)		
(FmCF)	(V <sub>DD</sub> )	(SYSDIV)	(tCYC)	(ADDIV)	12bit AD	8bit AD	
CF-12MHz	4.0V to 5.5V	1/1	250ns	1/8	34.8µs	21.5µs	
CF-12IVIFIZ	3.0V to 5.5V	1/1	250ns	1/16	69.5µs	42.8µs	
CF-10MHz	4.0V to 5.5V	1/1	300ns	1/8	41.8µs	25.8µs	
CF-10IVIEZ	3.0V to 5.5V	1/1	300ns	1/16	83.4µs	51.4µs	
OF AMILE	3.0V to 5.5V	1/1	750ns	1/8	104.5μs	64.5µs	
CF-4MHz	2.4V to 3.6V	1/1	750ns	1/32	416.5μs	256.5μs	

- Note 6-1: The quantization error  $(\pm 1/2LSB)$  must be excluded from the absolute accuracy. The absolute accuracy must be measured in the microcontroller's state in which no I/O operations occur at the pins adjacent to the analog input channel.
- Note 6-2: The conversion time refers to the period from the time an instruction for starting a conversion process till the time the conversion results register(s) are loaded with a complete digital conversion value corresponding to the analog input value.

The conversion time is 2 times the normal-time conversion time when:

- The first AD conversion is performed in the 12-bit AD conversion mode after a system reset.
- The first AD conversion is performed after the AD conversion mode is switched from 8-bit to 12-bit conversion mode.

### Power-on Reset (POR) Characteristics at $Ta = -40^{\circ}C$ to $+85^{\circ}C$ , $V_{SS}1 = V_{SS}2 = 0V$

					Specif	ication		
Parameter	Symbol	Pin/Remarks	Conditions	Option selected voltage	min	typ	max	unit
POR release	PORRL		Select from option.	1.67V	1.55	1.67	1.79	
voltage			(Note 7-1)	1.97V	1.85	1.97	2.09	
				2.07V	1.95	2.07	2.19	
				2.37V	2.25	2.37	2.49	
				2.57V	2.45	2.57	2.69	
				2.87V	2.75	2.87	2.99	V
				3.86V	3.73	3.86	3.99	
				4.35V	4.21	4.35	4.49	
Detection voltage unknown state	POUKS		• See Fig. 7. (Note 7-2)			0.7	0.95	
Power supply rise time	PORIS		Power supply rise time from 0V to 1.6V.				100	ms

Note7-1: The POR release level can be selected out of 8 levels only when the LVD reset function is disabled.

Note7-2: POR is in an unknown state before transistors start operation.

### Low Voltage Detection Reset (LVD) Characteristics at Ta = -40°C to +85°C, VSS1=VSS2=0V

						Specific	cation	
Parameter	Symbol	Pin/Remarks	Conditions	Option selected voltage	min	typ	max	unit
LVD reset Voltage	LVDET		Select from option.	1.91V	1.81	1.91	2.01	
(Note 8-2)			(Note 8-1)	2.01V	1.91	2.01	2.11	
			(Note 8-3) • See Fig. 8.	2.31V	2.21	2.31	2.41	
			• See Fig. 6.	2.51V	2.41	2.51	2.61	V
				2.81V	2.71	2.81	2.91	
				3.79V	3.69	3.79	3.89	
				4.28V	4.18	4.28	4.38	
LVD hysteresys	LVHYS			1.91V		55		
width				2.01V		55		
				2.31V		55		
				2.51V		55		mV
				2.81V		60		
				3.79V		65		
				4.28V		65		
Detection voltage unknown state	LVUKS		• See Fig. 8. (Note 8-4)			0.7	0.95	٧
Low voltage detection minimum Width (Reply sensitivity)	TLVDW		• LVDET-0.5V • See Fig. 9.		0.2			ms

Note8-1: The LVD reset level can be selected out of 7 levels only when the LVD reset function is enabled.

Note8-2: LVD reset voltage specification values do not include hysteresis voltage.

Note8-3: LVD reset voltage may exceed its specification values when port output state changes and/or when a large current flows through port.

Note8-4: LVD is in an unknown state before transistors start operation.

### Consumption Current Characteristics at $Ta = -40^{\circ}C$ to $+85^{\circ}C$ , $V_{SS}1 = V_{SS}2 = 0V$

Parameter Symbol Pin/ Co			Conditions			Specif	ication	
Parameter	Symbol	Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
Normal mode consumption current	IDDOP(1)	V <sub>DD</sub> 1	FmCF=12MHz ceramic oscillation mode     System clock set to 12MHz side     Internal low speed and medium speed RC	2.7 to 5.5		7.4	13.0	
(Note 9-1) (Note 9-2)			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/1 frequency division ratio	2.7 to 3.6		4.4	8.1	
	IDDOP(2)		CF1=24MHz external clock     System clock set to CF1 side     Internal low speed and medium speed RC	3.0 to 5.5		9.7	16.2	
			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/2 frequency division ratio	3.0 to 3.6		5.3	8.7	
	IDDOP(3)		FmCF=10MHz ceramic oscillation mode     System clock set to 10MHz side     Internal low speed and medium speed RC	2.2 to 5.5		6.6	11.9	
			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/1 frequency division ratio	2.2 to 3.6		4.0	7.4	
	IDDOP(4)		FmCF=4MHz ceramic oscillation mode     System clock set to 4MHz side     Internal low speed and medium speed RC	1.8 to 5.5		2.9	6.5	
			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/1 frequency division ratio	1.8 to 3.6		2.2	4.2	mA
	IDDOP(5)		CF oscillation low amplifier size selected. (CFLAMP=1) FmCF=4MHz ceramic oscillation mode System clock set to 4MHz side	2.2 to 5.5		1.1	2.5	
			Internal low speed and medium speed RC oscillation stopped.     Frequency variable RC oscillation stopped.     1/4 frequency division ratio	2.2 to 3.6		0.6	1.3	
	IDDOP(6)		FsX'tal=32.768kHz crystal oscillation mode     Internal low speed RC oscillation stopped.     System clock set to internal medium speed	1.8 to 5.5		0.6	1.7	
			RC oscillation.  • Frequency variable RC oscillation stopped.  • 1/2 frequency division ratio	1.8 to 3.6		0.3	0.9	
	IDDOP(7)		FsX'tal=32.768kHz crystal oscillation mode     Internal low speed and medium speed RC oscillation stopped.	2.7 to 5.5		5.0	9.1	
			System clock set to 8MHz with frequency variable RC oscillation     1/1 frequency division ratio	2.7 to 3.6		3.6	5.8	
	IDDOP(8)		External FsX'tal and FmCF oscillation stopped.     System clock set to internal low speed RC oscillation.	1.8 to 5.5		75	370	
			<ul> <li>Internal medium speed RC oscillation sopped.</li> <li>Frequency variable RC oscillation stopped.</li> <li>1/1 frequency division ratio</li> </ul>	1.8 to 3.6		46	192	
	IDDOP(9)		External FsX'tal and FmCF oscillation stopped.     System clock set to internal low speed RC oscillation.	5.0		75	176	μA
			Internal medium speed RC oscillation sopped.     Frequency variable RC oscillation stopped.	3.3		46	115	
			1/1 frequency division ratio     Ta=-10 to +50°C	2.5		35	85	

Note9-1: Values of the consumption current do not include current that flows into the output transistors and internal pull-up resistors.

Note9-2: The consumption current values do not include operational current of LVD function if not specified.

Continued on next page.

Continued from preceding page.

Parameter	Symbol	Pin/	Conditions	_		Speci	fication	
Farameter	Symbol	Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
Normal mode consumption current	IDDOP(10)	V <sub>DD</sub> 1	FsX'tal=32.768kHz crystal oscillation mode     System clock set to 32.768kHz side     Internal low speed and medium speed RC	1.8 to 5.5		38	139	
(Note 9-1) (Note 9-2)			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/2 frequency division ratio	1.8 to 3.6		15	66	
	IDDOP(11)		FsX'tal=32.768kHz crystal oscillation mode     System clock set to 32.768kHz side	5.0		38	101	μΑ
			Internal low speed and medium speed RC oscillation stopped.	3.3		15	46	
			Frequency variable RC oscillation stopped.     1/2 frequency division ratio     Ta=-10 to +50°C	2.5		9.0	28	
HALT mode consumption current (Note 9-1)	IDDHALT(1)	V <sub>DD</sub> 1	HALT mode     FmCF=12MHz ceramic oscillation mode     System clock set to 12MHz side     Internal low speed and medium speed RC	2.7 to 5.5		3.1	5.6	
(Note 9-2)			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/1 frequency division ratio	2.7 to 3.6		1.6	2.9	
	IDDHALT(2)		HALT mode     CF1=24MHz external clock     System clock set to CF1 side     Internal low speed and medium speed RC	3.0 to 5.5		4.9	8.6	
			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/2 frequency division ratio	3.0 to 3.6		2.3	3.8	
	IDDHALT(3)		HALT mode     FmCF=10MHz ceramic oscillation mode     System clock set to 10MHz side     Internal low speed and medium speed RC	2.2 to 5.5		2.7	5.3	
			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/1 frequency division ratio	2.2 to 3.6		1.4	2.6	
	IDDHALT(4)		HALT mode     FmCF=4MHz ceramic oscillation mode     System clock set to 4MHz side     Internal low speed and medium speed RC	1.8 to 5.5		1.4	3.5	mA
			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/1 frequency division ratio	1.8 to 3.6		0.7	1.3	
	IDDHALT(5)		HALT mode     CF oscillation low amplifier size selected.     (CFLAMP=1)     FmCF=4MHz ceramic oscillation mode	2.2 to 5.5		0.7	1.8	
			System clock set to 4MHz side     Internal low speed and medium speed RC oscillation stopped.     Frequency variable RC oscillation stopped.     1/4 frequency division ratio	2.2 to 3.6		0.3	0.7	
	IDDHALT(6)	HALT mode     FsX'tal=32.768kHz crystal oscillation mode     Internal low speed RC oscillation stopped.     System clock set to internal medium speed	1.8 to 5.5		0.4	1.1		
			RC oscillation Frequency variable RC oscillation stopped.  1/2 frequency division ratio	1.8 to 3.6		0.2	0.5	

Note9-1: Values of the consumption current do not include current that flows into the output transistors and internal pull-up resistors.

Note9-2: The consumption current values do not include operational current of LVD function if not specified.

Continued on next page.

Continued from preceding page.

Parameter	Symbol	Pin/	Conditions			Specif	ication	
Falametei	Symbol	remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit
HALT mode consumption current (Note 9-1)	IDDHALT(7)	V <sub>DD</sub> 1	HALT mode     FsX'tal=32.768kHz crystal oscillation mode     Internal low speed and medium speed RC oscillation stopped.	2.7 to 5.5		1.8	3.5	
(Note 9-2)			System clock set to 8MHz with frequency variable RC oscillation     1/1 frequency division ratio	2.7 to 3.6		1.1	2.0	
	IDDHALT(8)		HALT mode     External FsX'tal and FmCF oscillation stopped.     System clock set to internal low speed RC	1.8 to 5.5		23	260	
			oscillation.  Internal medium speed RC oscillation sopped.  Frequency variable RC oscillation stopped.  1/1 frequency division ratio	1.8 to 3.6		13	119	μΑ
	IDDHALT(9)		HALT mode     External FsX'tal and FmCF oscillation stopped.     System clock set to internal low speed RC	5.0		23	65	
			oscillation.  • Internal medium speed RC oscillation sopped.	3.3		13	35	
			Frequency variable RC oscillation stopped.     1/1 frequency division ratio     Ta=-10 to +50°C	2.5		9.2	25	
	IDDHALT(10)		HALT mode     FsX'tal=32.768kHz crystal oscillation mode     System clock set to 32.768kHz side     Internal low speed and medium speed RC	1.8 to 5.5		25	112	μА
			oscillation stopped.  • Frequency variable RC oscillation stopped.  • 1/2 frequency division ratio	1.8 to 3.6		8.5	56	<b>.</b>
	IDDHALT(11)		HALT mode     FsX'tal=32.768kHz crystal oscillation mode     System clock set to 32.768kHz side	5.0		25	69	
			Internal low speed and medium speed RC oscillation stopped.     Frequency variable RC oscillation stopped.	3.3		8.5	29	
			1/2 frequency division ratio     Ta=-10 to +50°C	2.5		4.2	15	
HOLD mode	IDDHOLD(1)	V <sub>DD</sub> 1	HOLD mode	1.8 to 5.5		0.04	30	
consumption current			CF1=V <sub>DD</sub> or open (External clock mode)	1.8 to 3.6		0.02	21	
(Note 9-1)	IDDHOLD(2)		<ul> <li>HOLD mode</li> <li>◆ CF1=V<sub>DD</sub> or open (External clock mode)</li> </ul>	5.0		0.04	2.3	
(Note 9-2)			• Ta=-10 to +50°C	3.3		0.02	1.5	
	.===.			2.5		0.017	1.2	
	IDDHOLD(3)		HOLD mode     CF1=V <sub>DD</sub> or open (External clock mode)     LVD option selected	1.8 to 5.5 1.8 to 3.6		3.2 2.7	35 24	
	IDDHOLD(4)	†	HOLD mode	5.0		3.2	6.5	μΑ
	( · /		CF1=V <sub>DD</sub> or open (External clock mode)	3.3		2.7	4.5	•
			• Ta=-10 to +50°C					
Times UOLD	IDDITION DATE:	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	LVD option selected  Times LIOLD and the	2.5		2.5	4.2	
Timer HOLD mode	IDDHOLD(5)	V <sub>DD</sub> 1	Timer HOLD mode  • FsX'tal=32.768 kHz crystal oscillation mode	1.8 to 5.5		22	106	
consumption	IDDITIC: 5/6	-		1.8 to 3.6		7.5	45	
current	IDDHOLD(6)		Timer HOLD mode  • FsX'tal=32.768kHz crystal oscillation mode	5.0		22	62	
(Note 9-1)			• Ta=-10 to +50°C	3.3		7.5	23	
(Note 9-2)				2.5		2.9	12	

Note9-1: Values of the consumption current do not include current that flows into the output transistors and internal pull-up resistors.

Note9-2: The consumption current values do not include operational current of LVD function if not specified.

### F-ROM Programming Characteristics at $Ta = +10^{\circ}C$ to $+55^{\circ}C$ , $V_{SS}1 = V_{SS}2 = 0V$

Doromotor	Cumahad	Pin/Remarks	Conditions		Specification				
Parameter	Symbol	Pin/Remarks	Conditions	V <sub>DD</sub> [V]	min	typ	max	unit	
Onboard	IDDFW(1)	V <sub>DD</sub> 1	Only current of the Flash block.						
programming				2.2 to 5.5		5	10	mA	
current									
Programming	tFW(1)		Erasing time	2.240.5.5		20	30	ms	
time	tFW(2)		Programming time	2.2 to 5.5		40	60	μs	

### **UART (Full Duplex) Operating Conditions** at $Ta = -40^{\circ}C$ to $+85^{\circ}C$ , $V_{SS}1 = V_{SS}2 = 0V$

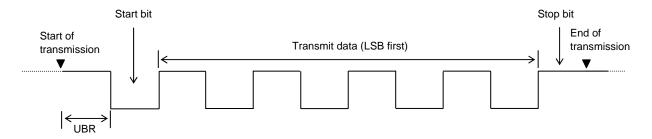
Parameter	Symbol	Pin/Remarks	0 177		Specification				
			Conditions	V <sub>DD</sub> [V]	min	typ	max	unit	
Transfer rate	UBR	UTX(P20) URX(P21)		1.8 to 5.5	16/3		8192/3	tCYC	

Data length: 7/8/9 bits (LSB first)

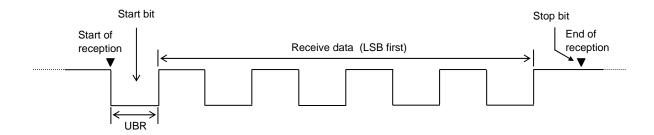
Stop bits: 1 bit (2-bit in continuous data transmission)

Parity bits: None

Example of Continuous 8-bit Data Transmission Mode Processing (First Transmit Data=55H)



Example of Continuous 8-bit Data Reception Mode Processing (First Receive Data=55H)



### Characteristics of a Sample Main System Clock Oscillation Circuit

Given below are the characteristics of a sample main system clock oscillation circuit that are measured using a SANYO-designated oscillation characteristics evaluation board and external components with circuit constant values with which the oscillator vendor confirmed normal and stable oscillation.

Table 1 Characteristics of a Sample Main System Clock Oscillator Circuit with a Ceramic Oscillator

• CF oscillation normal amplifier size selected (CFLAMP=0)

### **■**MURATA

Nominal Type	_		Circuit Constant				Operating	Oscillation Stabilization Time		
	Oscillator Name	C1 [pF]	C2 [pF]	Rf [Ω]	Rd [Ω]	Voltage Range [V]	typ [ms]	max [ms]	Remarks	
12MHz	SMD	CSTCE12M0G52-R0	(10)	(10)	Open	1.0k	2.7 to 5.5	0.1	0.5	
	CMD	SMD CSTCE10M0G52-R0	(10)	(10)	Open	680	2.2 to 3.6	0.1	0.5	Internal C1.C2
10MHz	SIVID				Open	1.0k	2.3 to 5.5	0.1	0.5	
	LEAD	CSTLS10M0G53-B0	(15)	(15)	Open	1.0k	2.5 to 5.5	0.1	0.5	
OMI I=	SMD	CSTCE8M00G52-R0	(10)	(10)	Open	1.5k	2.2 to 5.5	0.1	0.5	
8MHz	LEAD	CSTLS8M00G53-B0	(15)	(15)	Open	1.5k	2.2 to 5.5	0.1	0.5	
CNALL-	SMD	CSTCR6M00G53-R0	(15)	(15)	Open	2.2k	2.2 to 5.5	0.1	0.5	01,02
6MHz	LEAD	CSTLS6M00G53-B0	(15)	(15)	Open	2.2k	2.2 to 5.5	0.1	0.5	
	01.15	SMD CSTCR4M00G53-R0	(4 F)	(45)	Open	1.5k	1.8 to 2.7	0.2	0.6	
4MHz	SIVID		(15)	(15)	Open	3.3k	1.9 to 5.5	0.2	0.6	
	LEAD	CSTLS4M00G53-B0	(15)	(15)	Open	3.3k	1.9 to 5.5	0.2	0.6	

• CF oscillation low amplifier size selected (CFLAMP=1)

#### **■**MURATA

Nominal Ty Frequency	_	Oscillator Name	Circuit Constant				Operating	Oscillation Stabilization Time		
	Туре		C1 [pF]	C2 [pF]	Rf [Ω]	Rd [Ω]	Voltage Range [V]	Typ [ms]	Max [ms]	Remarks
4MHz —		CSTCR4M00G53-R0 CSTCR4M00G53095-R0	(15)	(15)	Open	1.0k	2.1 to 2.7	0.2	0.6	Internal C1,C2
	SMD				Open	2.2k	2.5 to 5.5	0.2	0.6	
			(15)	(15)	Open	1.0k	1.9 to 2.7	0.2	0.7	
		CSTLS4M00G53-B0 (15)  CSTLS4M00G53095-B0 (15)	(15)	(15)	Open	1.0k	2.2 to 2.7	0.2	0.6	
	LEAD				Open	2.2k	2.5 to 5.5	0.2	0.6	
			(15)	(15)	Open	1.0k	2.0 to 2.7	0.2	0.7	

The oscillation stabilization time refers to the time interval that is required for the oscillation to get stabilized after  $V_{DD}$  goes above the operating voltage lower limit (see Figure 3).

### **Characteristics of a Sample Subsystem Clock Oscillator Circuit**

Given below are the characteristics of a sample subsystem clock oscillation circuit that are measured using a SANYO-designated oscillation characteristics evaluation board and external components with circuit constant values with which the oscillator vendor confirmed normal and stable oscillation.

Table 2 Characteristics of a Sample Subsystem Clock Oscillator Circuit with a Crystal Oscillator

### ■EPSON TOYOCOM

Nominal Frequency	_	Oscillator Name	Circuit Constant				Operating	Oscillation Stabilization Time		Damada
	Туре		C1 [pF]	C2 [pF]	Rf [Ω]	Rd [Ω]	Voltage Range [V]	typ [s]	max [s]	Remarks
32.768kHz	SMD	MC-306	9	9	Open	330k	1.8 to 5.5	1.4	4.0	Applicable CL value = 7.0pF

The oscillation stabilization time refers to the time interval that is required for the oscillation to get stabilized after the instruction for starting the subclock oscillation circuit is executed and to the time interval that is required for the oscillation to get stabilized after the HOLD mode is reset (see Figure 3):

Note: The components that are involved in oscillation should be placed as close to the IC and to one another as possible because they are vulnerable to the influences of the circuit pattern.

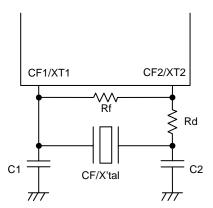


Figure 1 CF and XT Oscillator Circuit

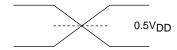
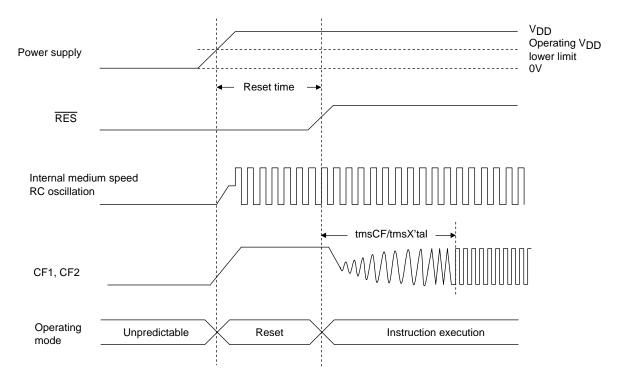
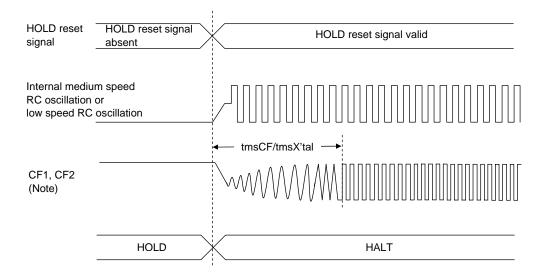


Figure 2 AC Timing Measurement Point



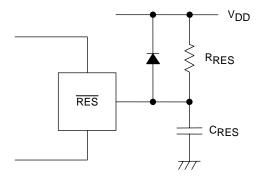
Reset Time and Oscillation Stabilization Time



HOLD Reset Signal and Oscillation Stabilization Time

Note: External oscillation circuit is selected.

Figure 3 Oscillation Stabilization Times



### Note:

External circuits for reset may vary depending on the usage of POR and LVD. Please refer to the user's manual for more information..

Figure 4 Reset Circuit

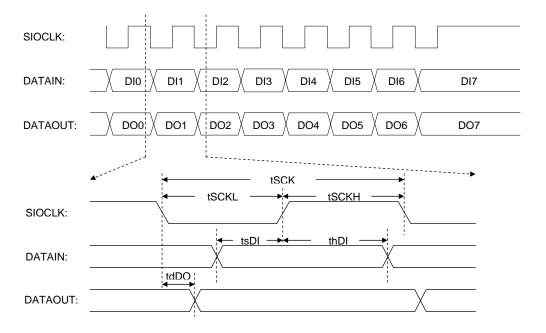


Figure 5 Serial I/O Output Waveforms

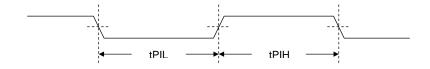


Figure 6 Pulse Input Timing Signal Waveform

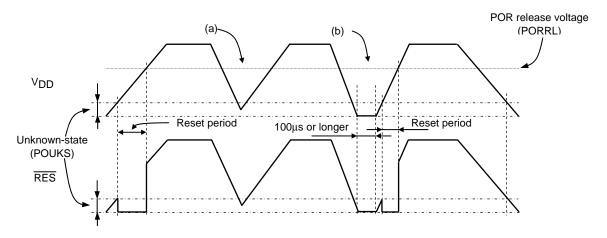


Figure 7 Waveform observed when only POR is used (LVD not used) (RESET pin: Pull-up resistor RRES only)

- The POR function generates a reset only when power is turned on starting at the VSS level.
- No stable reset will be generated if power is turned on again when the power level does not go down to the VSS level as shown in (a). If such a case is anticipated, use the LVD function together with the POR function or implement an external reset circuit.
- A reset is generated only when the power level goes down to the VSS level as shown in (b) and power is turned on again after this condition continues for 100µs or longer.

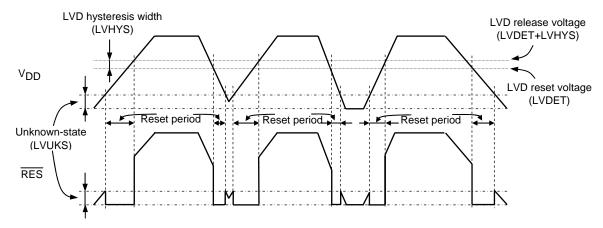


Figure 8 Waveform observed when both POR and LVD functions are used (RESET pin: Pull-up resistor  $R_{RES}$  only)

- Resets are generated both when power is turned on and when the power level lowers.
- A hysteresis width (LVHYS) is provided to prevent the repetitions of reset release and entry cycles near the detection level.

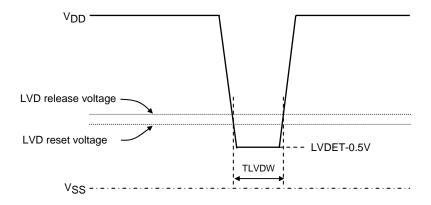


Figure 9 Low voltage detection minimum width (Example of momentary power loss/Voltage variation waveform)

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